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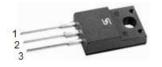


Taiwan Semiconductor

Trench Schottky Rectifier

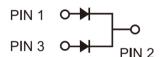
FEATURES

- Patented Trench Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Low power loss/ high efficiency
- High forward surge capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition



ITO-220AB







TYPICAL APPLICATIONS

Trench Schottky barrier rectifier are designed for high frequency miniature switched mode power supplies such as adapters, lighting and on-board DC/DC converters.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating

Packing code with suffix "G" means green compound (halogen-free)

Terminal: Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 2 whisker test

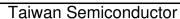
Polarity: As marked

Mounting torque: 0.56 Nm max. **Weight:** 1.7 g (approximately)

MAXIMUM RATINGS AND ELEC	TRICAL C	HARACTE	RISTICS (7	Γ _A = 25°C un	less otherwis	se noted)		
PARAMETER Maximum repetitive peak reverse voltage			SYMBOL	TSF20L45C TSF20L60C 45 60		TSF20L60C		VNIT
			V_{RRM}			60		
Maximum average forward rectified	per device		I _{F(AV)}	20				А
current	per diode			10				
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load per diode			I _{FSM}	120			А	
Voltage rate of change (rated V _R)			dV/dt	10000			V/µs	
				TYP	MAX	TYP	MAX	
Instantaneous forward voltage per diode (Note1)	I _F = 10A	T _J = 25°C		0.55	0.65	0.57	0.66	V
	I _F = 20A	$T_{J} = 25^{\circ}C$	- V _F	0.70	0.79	0.72	0.81	
	I _F = 10A			0.53	0.63	0.55	0.64	
	I _F = 20A	1 _J = 125 C		0.68	0.77	0.70	0.79	
Maximum instantaneous reverse current per diode at rated reverse voltage $T_J = 25^{\circ}C$ $T_J = 125^{\circ}C$			500				μA	
		$T_J = 125$ °C	l I _R	100				mA
Typical thermal resistance per diode			$R_{ heta JC}$	4				°C/W
Operating junction temperature range			T _J	- 55 to +150				°C
Storage temperature range			T_{STG}	- 55 to +150			°C	
Note 1: Dulce test with pulse width = 300u	c 10/ duty o	rolo.						

Note 1: Pulse test with pulse width = 300µs, 1% duty cycle

Document Number: DS_D1412005 Version: B14





ORDERING INFORMATION						
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING		
TSF20LXXC (Note 1)	C0	G	ITO-220AB	50 / Tube		

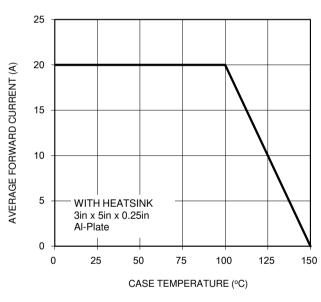
Note 1: "XX" defines voltage from 45V (TSF20L45C) to 60V (TSF20L60C)

EXAMPLE							
PREFERRED PART NO.		PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION			
TSF20L45C C0G	TSF20L45C	C0	G	Green compound			

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

FIG.1 FORWARD CURRENT DERATING CURVE



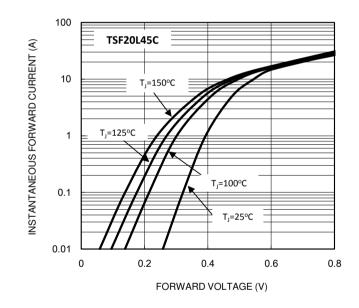


FIG. 3 TYPICAL FORWARD CHARACTERISTICS

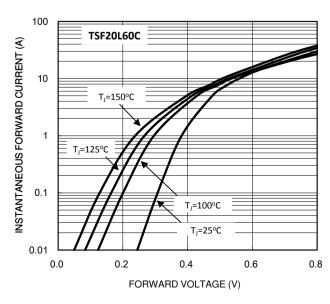
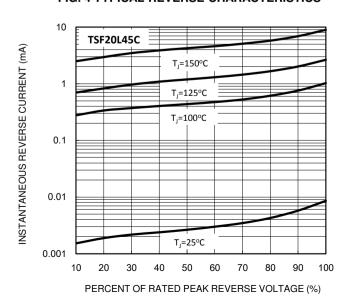


FIG. 4 TYPICAL REVERSE CHARACTERISTICS



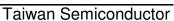




FIG. 5 TYPICAL REVERSE CHARACTERISTICS

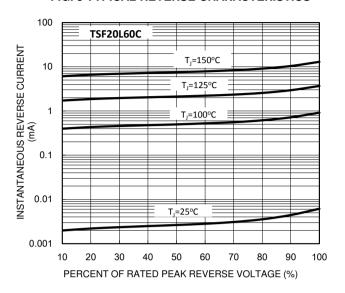
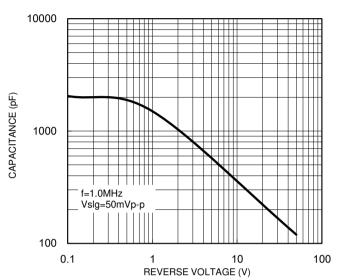
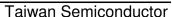


FIG. 6 TYPICAL JUNCTION CAPACITANCE

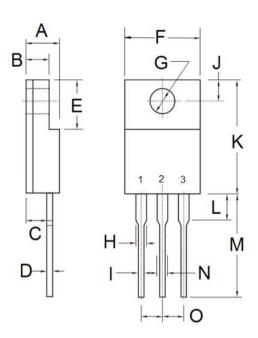






PACKAGE OUTLINE DIMENSIONS

ITO-220AB



DIM.	Unit	(mm)	Unit (inch)		
Diw.	Min	Max	Min	Max	
Α	4.30	4.70	0.169	0.185	
В	2.50	3.16	0.098	0.124	
С	2.30	2.96	0.091	0.117	
D	0.46	0.76	0.018	0.030	
Е	6.30	6.90	0.248	0.272	
F	9.60	10.30	0.378	0.406	
G	3.00	3.40	0.118	0.134	
Н	0.95	1.45	0.037	0.057	
	0.50	0.90	0.020	0.035	
J	2.40	3.20	0.094	0.126	
K	14.80	15.50	0.583	0.610	
L	-	4.10	ı	0.161	
М	12.60	13.80	0.496	0.543	
N	-	1.80	-	0.071	
0	2.41	2.67	0.095	0.105	

MARKING DIAGRAM



P/N = Specific Device Code

G = Green Compound

YWW = Date Code = Factory Code



Taiwan Semiconductor

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Document Number: DS D1412005 Version: B14